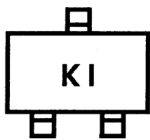


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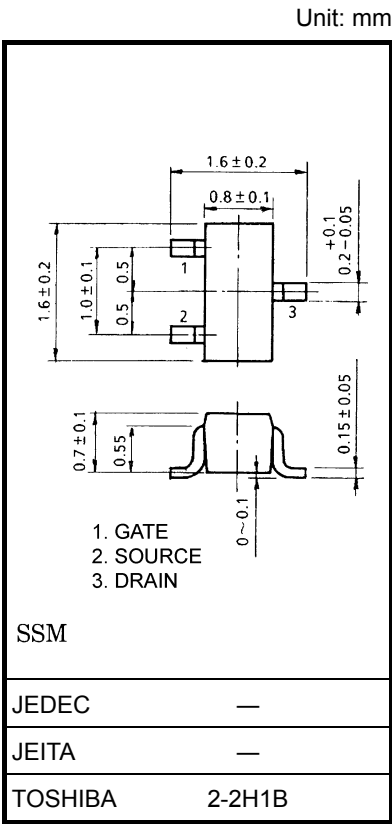
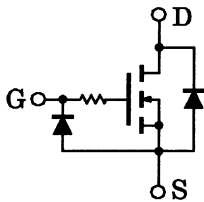
High Speed Switching Applications  
Analog Switch Applications

- 2.5 V gate drive
- Low threshold voltage:  $V_{th} = 0.5 \sim 1.5$  V
- High speed
- Enhancement mode
- Small package

Marking



Equivalent Circuit



Weight: 2.4 mg (typ.)

Absolute Maximum Ratings ( $T_a = 25^{\circ}\text{C}$ )

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DS}$	20	V
Gate-source voltage	$V_{GSS}$	10	V
DC drain current	$I_D$	50	mA
Drain power dissipation	$P_D$	100	mW
Channel temperature	$T_{ch}$	150	$^{\circ}\text{C}$
Storage temperature range	$T_{stg}$	$-55 \sim 150$	$^{\circ}\text{C}$

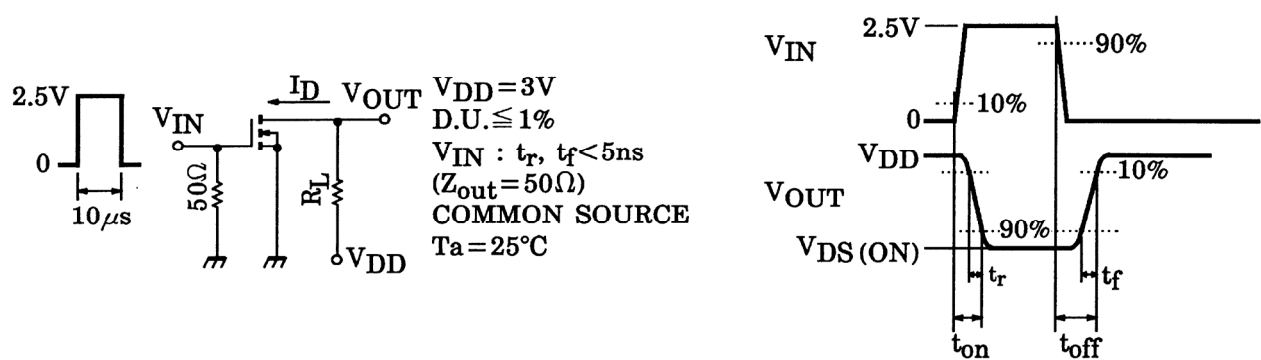
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.  
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: This transistor is electrostatic sensitive device.  
Please handle with caution.

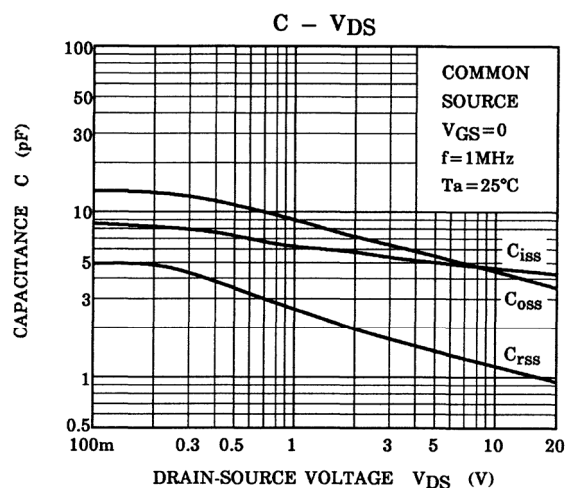
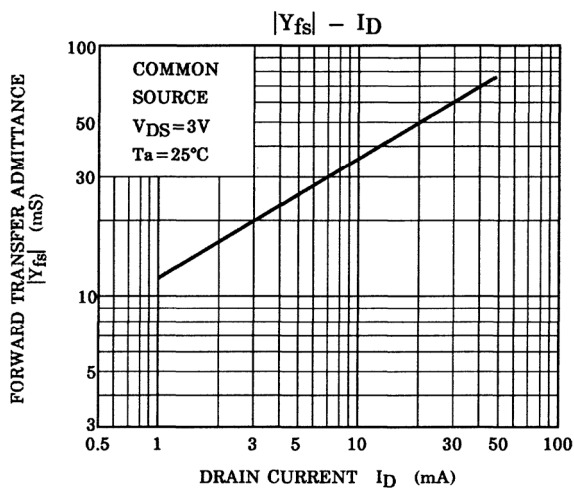
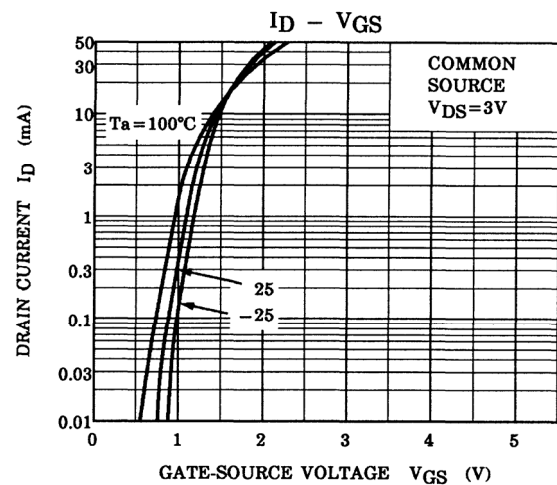
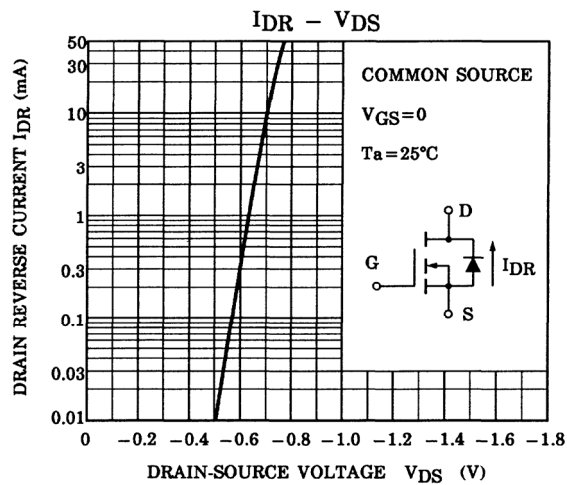
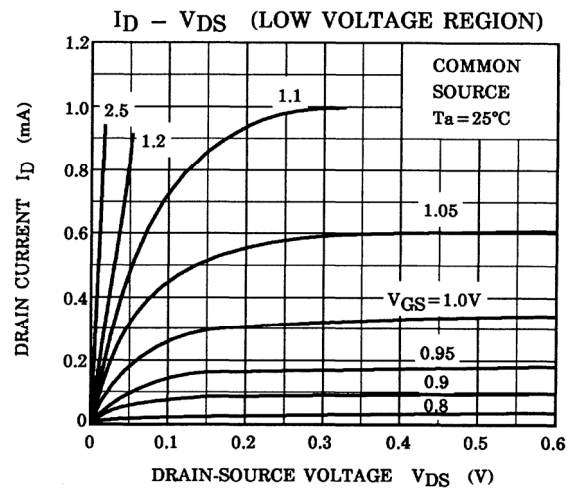
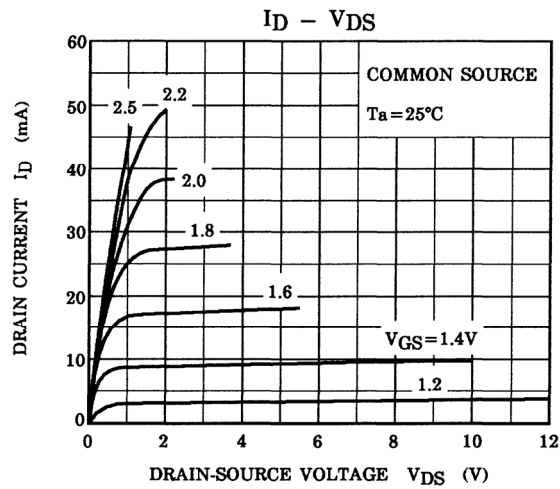
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Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = 10\text{ V}, V_{DS} = 0$	—	—	1	$\mu\text{A}$
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 100\text{ }\mu\text{A}, V_{GS} = 0$	20	—	—	V
Drain cut-off current	$I_{DSS}$	$V_{DS} = 20\text{ V}, V_{GS} = 0$	—	—	1	$\mu\text{A}$
Gate threshold voltage	$V_{th}$	$V_{DS} = 3\text{ V}, I_D = 0.1\text{ mA}$	0.5	—	1.5	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 10\text{ mA}$	20	—	—	mS
Drain-source ON resistance	$R_{DS(ON)}$	$I_D = 10\text{ mA}, V_{GS} = 2.5\text{ V}$	—	20	40	$\Omega$
Input capacitance	$C_{iss}$	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	5.5	—	pF
Reverse transfer capacitance	$C_{rss}$	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	1.6	—	pF
Output capacitance	$C_{oss}$	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	6.5	—	pF
Switching time	Turn-on time	$V_{DD} = 3\text{ V}, I_D = 10\text{ mA}, V_{GS} = 0 \sim 2.5\text{ V}$	—	0.14	—	$\mu\text{s}$
	Turn-off time	$V_{DD} = 3\text{ V}, I_D = 10\text{ mA}, V_{GS} = 0 \sim 2.5\text{ V}$	—	0.14	—	

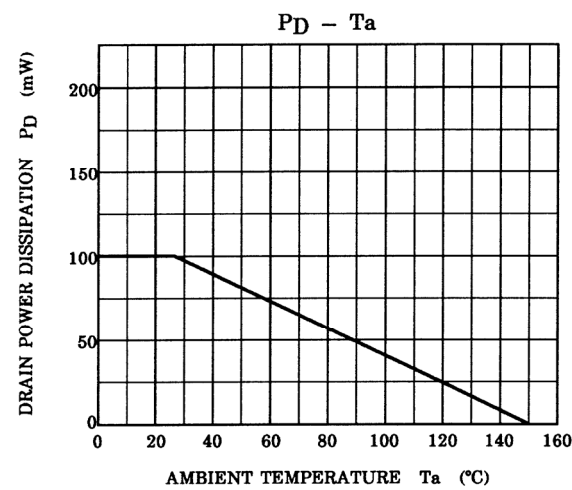
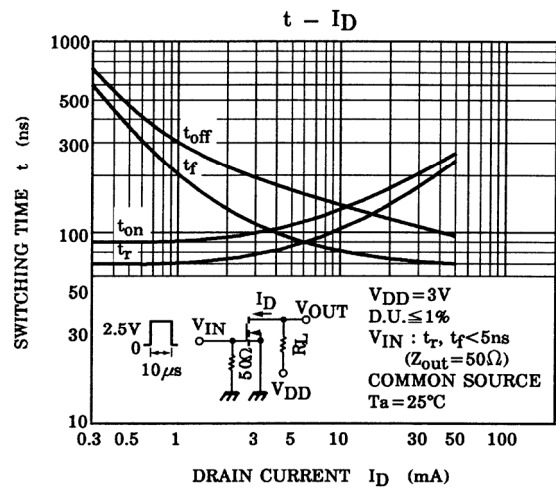
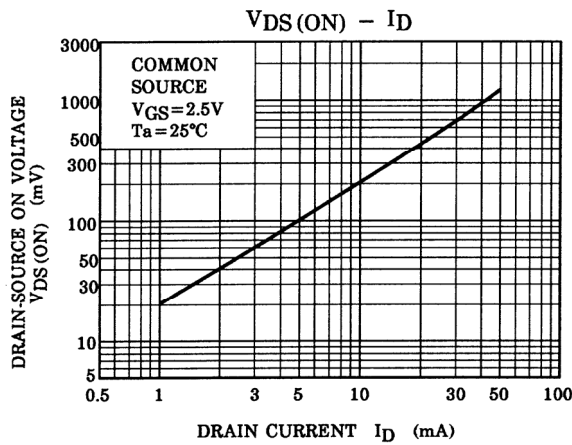
Switching Time Test Circuit



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